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LE OF SUP	stitute for form 1449A/PTO			Application Number	10/668693		
IN	IFORMATION DISCL	06	IDE	Filing Date	9/23/2003		
				First Named Inventor	Mahaiani et al.		
S	TATEMENT BY APP	LIC	ANI	Art Unit	2826		
	(Use as many sheets as neces	sary)		Examiner Name	VICTOR A. MANDALA		
Sheet	1	of	1	Attorney Docket Number	MA-105		

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Examiner Initials*	Cite No.	Number - Kind Code ^{2 (8 known)}	MM-DD-YYYY	Applicant of Cited Document	Figures Appear		
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Application Number 10/668693 September 23, 2003 Filing Date First Named Inventor Mahajani, Maitreyee **Group Art Unit** 2811 Unknown **Examiner Name** Attorney Docket No: MA-105 Sheet 1 of 1

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